HALOGEN

FREE



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Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.28 \text{ V}$ at $I_F = 5 \text{ A}$





PRIMARY CHARACTERISTICS				
I _{F(DC)}	40 A			
V_{RRM}	45 V			
I _{FSM}	240 A			
V _F at I _F = 40 A	0.51 V			
T _{OP} max. (AC mode)	150 °C			
T _J max. (DC forward current)	200 °C			
Package	ITO-220AC			
Diode variation	Single die			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: ITO-220AC

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	SYMBOL VFT4045BP		
Maximum repetitive peak reverse voltage	V_{RRM}	45	V	
Maximum DC forward bypassing current (fig. 1)	I _{F(DC)} (1)	40	Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	240	А	
Operating junction temperature range (AC mode)	T _{OP}	-40 to +150	°C	
Isolation voltage from termal to heatsink t = 1 min	V _{AC}	1500	V	
Junction temperature in DC forward current without reverse bias, $t \le 1 \text{ h}$	T _J ⁽²⁾	≤ 200	°C	

Notes

- (1) With heatsink
- (2) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	- V _F ⁽¹⁾	0.41	-	. V	
	I _F = 20 A			0.50	-		
	I _F = 40 A			0.57	0.67		
	I _F = 5 A	T _A = 125 °C		0.28	-		
	I _F = 20 A			0.41	-		
	I _F = 40 A			0.51	0.63		
Reverse current	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	3000	μA	
	v _R = 45 v	T _A = 125 °C		29	85	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL VFT4045BP			
Typical thermal resistance	$R_{ heta JC}$	4.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AC	VFT4045BP-M3/4W	1.75	4W	50/tube	Tube	

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

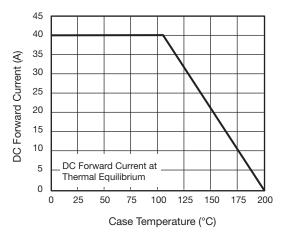


Fig. 1 - Maximum Forward Current Derating Curve

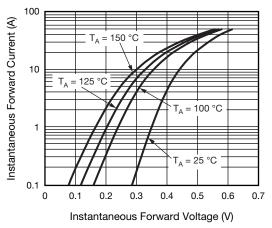


Fig. 2 - Typical Instantaneous Forward Characteristics

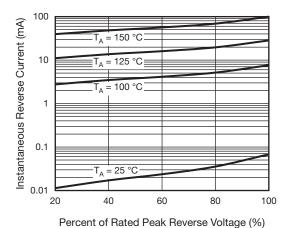


Fig. 3 - Typical Reverse Characteristics

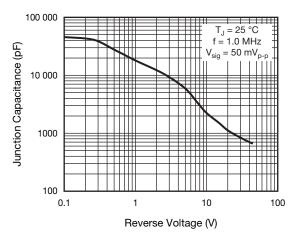


Fig. 4 - Typical Junction Capacitance

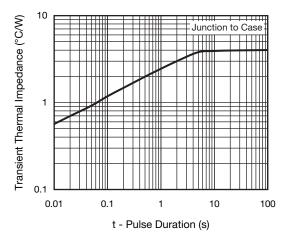
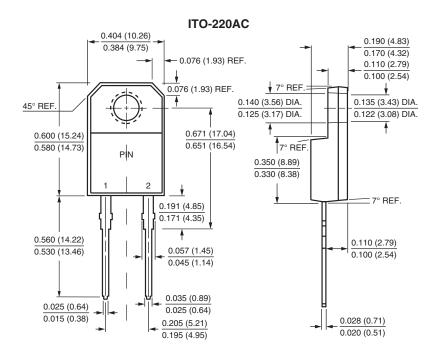


Fig. 5 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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